# Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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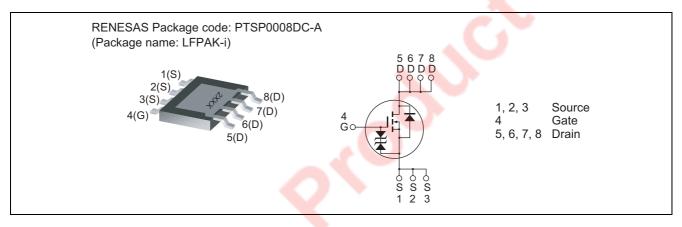
# HAT2174N Silicon N Channel Power MOS FET Power Switching

REJ03G1685-0200
Rev.2.00
May 28, 2008

### Features

- Capable of 8 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
  - $R_{DS(on)} = 21.3 \text{ m}\Omega \text{ typ.} (at V_{GS} = 10 \text{ V})$

### Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$	
Item	Symbol	Ratings	Unit	
Drain to source voltage	V <sub>DSS</sub>	100	V	
Gate to source voltage	V <sub>GSS</sub>	±20	V	
Drain current	I <sub>D</sub>	20	A	
Drain peak current	I <sub>D(pulse)</sub> Note1	80	A	
Body-drain diode reverse drain current	I <sub>DR</sub>	20	A	
Avalanche current	I <sub>AP</sub> Note 2	20	A	
Avalanche energy	E <sub>AR</sub> Note 2	40	mJ	
Channel dissipation	Pch <sup>Note3</sup>	20	W	
Channel to case thermal resistance	θch-C	6.25	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tch =  $25^{\circ}$ C, Rg  $\geq 50 \Omega$ 

3. Tc = 25°C

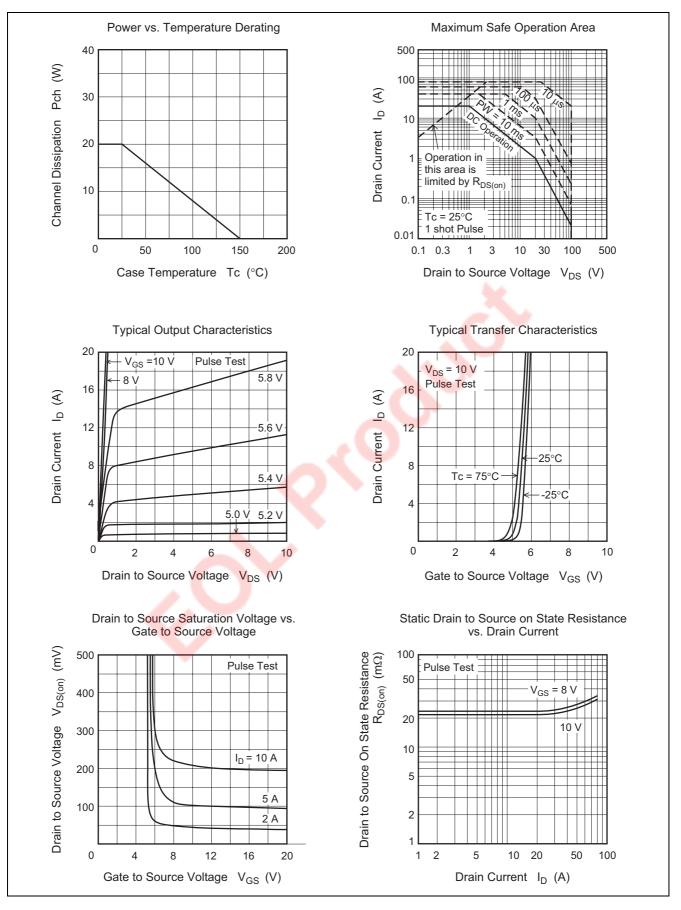
# **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	100	_	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 100 V, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	4.0	_	6.0	V	$V_{DS} = 10 \text{ V}, I_D = 20 \text{mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	21.3	27.3	mΩ	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R <sub>DS(on)</sub>	_	22.3	30.3	mΩ	$I_D = 10 \text{ A}, V_{GS} = 8 \text{ V}^{Note4}$
Forward transfer admittance	y <sub>fs</sub>	21	35	_	S	$I_D = 10 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	2280	_	pF	$V_{DS} = 10 V, V_{GS} = 0,$
Output capacitance	Coss	_	285	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss		100		pF	
Gate resistance	Rg	_	0.5	_	Ω	
Total gate charge	Qg	_	33.5	_	nC	$V_{DD} = 50 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	12.4	_	nC	I <sub>D</sub> = 20 A
Gate to drain charge	Qgd		8.4		nC	
Turn-on delay time	t <sub>d(on)</sub>		18		ns	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A},$
Rise time	tr		13		ns	V <sub>DD</sub> ≅ 30 V, R <sub>L</sub> = 3 Ω,
Turn-off delay time	t <sub>d(off)</sub>		31	_	ns	$Rg = 4.7 \Omega$
Fall time	t <sub>f</sub>	_	5.5		ns	]
Body-drain diode forward voltage	V <sub>DF</sub>		0.84	<b>1.10</b>	V	$I_F = 20 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t <sub>rr</sub>		50	1	ns	$I_F = 20 \text{ A}, V_{GS} = 0$
time						di <sub>F</sub> / dt = 100 A/ μs

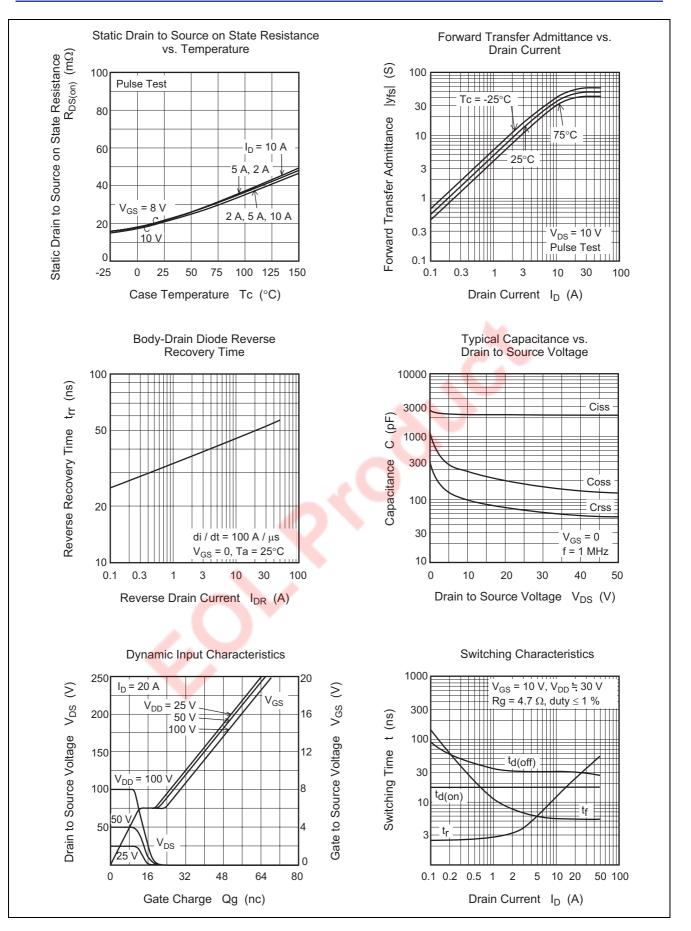
Notes: 4. Pulse test

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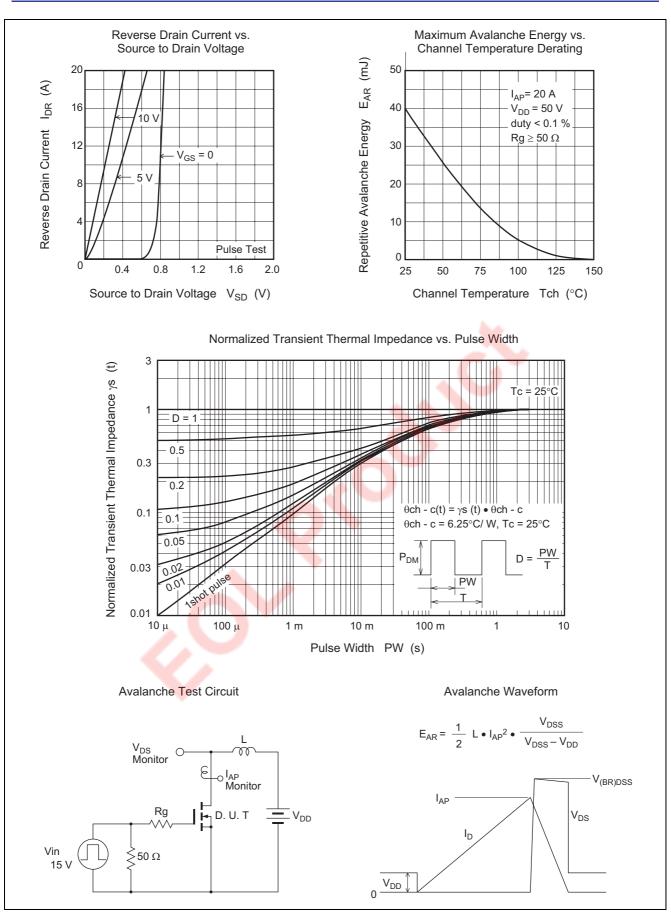
### **Main Characteristics**



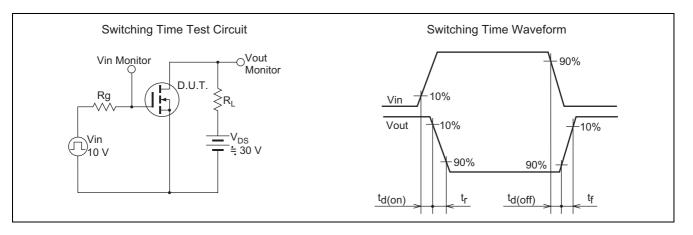
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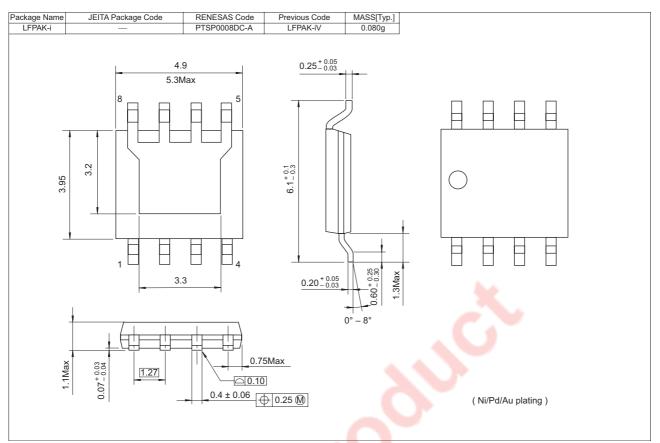
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### **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
HAT2174N-EL-E	2500 pcs 📃	Taping

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